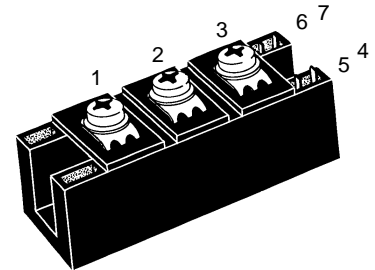


Thyristor Modules

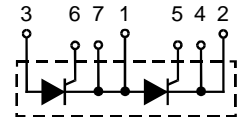
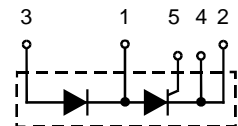
Thyristor/Diode Modules

$I_{TRMS} = 2x 300 A$
 $I_{TAVM} = 2x 190 A$
 $V_{RRM} = 800-1800 V$

V_{RSM}	V_{RRM}	Type	
V_{DSM}	V_{DRM}		
V	V	Version 1	Version 1
900	800	MCC 162-08io1	MCD 162-08io1
1300	1200	MCC 162-12io1	MCD 162-12io1
1500	1400	MCC 162-14io1	MCD 162-14io1
1700	1600	MCC 162-16io1	MCD 162-16io1
1900	1800	MCC 162-18io1	MCD 162-18io1



Symbol	Test Conditions	Maximum Ratings	
I_{TRMS}^* I_{FRMS} I_{TAVM}^* I_{FAVM}	$T_{VJ} = T_{VJM}$	300	A
	$T_C = 80^\circ C; 180^\circ$ sine	190	A
	$T_C = 85^\circ C; 180^\circ$ sine	181	A
I_{TSM}^* I_{FSM}	$T_{VJ} = 45^\circ C;$ $V_R = 0$	$t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	6000 A 6400 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	5250 A 5600 A
$\int i^2 dt$	$T_{VJ} = 45^\circ C$ $V_R = 0$	$t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	180 000 A^2s 170 000 A^2s
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	137 000 A^2s 128 000 A^2s
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $f = 50$ Hz, $t_p = 200$ μs $V_D = 2/3 V_{DRM}$ $I_G = 0.5$ A $di_G/dt = 0.5$ A/ μs	repetitive, $I_T = 500$ A	150 A/ μs
	$T_{VJ} = T_{VJM};$ $R_{GK} = \infty;$ method 1 (linear voltage rise)	$V_{DR} = 2/3 V_{DRM}$	1000 V/ μs
P_{GM}	$T_{VJ} = T_{VJM}$	$t_p = 30$ μs	120 W
	$I_T = I_{TAVM}$	$t_p = 500$ μs	60 W
P_{GAV}			8 W
V_{RGM}			10 V
T_{VJ}		-40...+125	$^\circ C$
T_{VJM}		125	$^\circ C$
T_{sig}		-40...+125	$^\circ C$
V_{ISOL}	50/60 Hz, RMS	$t = 1$ min	3000 V~
	$I_{ISOL} \leq 1$ mA	$t = 1$ s	3600 V~
M_d	Mounting torque (M6)	2.25-2.75/20-25	Nm/lb.in.
	Terminal connection torque (M6)	4.5-5.5/40-48	Nm/lb.in.
Weight	Typical including screws		125 g

MCC

MCD

Features

- International standard package
- Direct copper bonded Al_2O_3 -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873
- Keyed gate/cathode twin pins

Applications

- Motor control
- Power converter
- Heat and temperature control for industrial furnaces and chemical processes
- Lighting control
- Contactless switches

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions